

Supplementary Information

Preferential Perovskite Surface-termination Induced High Piezoresponse in Lead-free *in-situ* Fabricated Cs₃Bi₂Br₉-PVDF Nanocomposites Promotes Biomechanical Energy Harvesting

Aditi Sahoo¹, Tufan Paul¹, Ankan Nath², Soumen Maiti³, Prabhat Kumar¹, Prasenjit Ghosh²
and Rupak Banerjee^{1, 4*}

¹Department of Physics, Indian Institute of Technology Gandhinagar, Palaj, Gandhinagar 382355, India

²Department of Physics, Indian Institute of Science Education and Research, Dr. Homi Bhabha Road, Pune 411008, India

³ St. Thomas Colleges of Engineering & Technology, Kolkata 700023, India

⁴K C Patel Centre for Sustainable Development, Indian Institute of Technology Gandhinagar, Palaj, Gandhinagar 382355, India

*Corresponding author email: rupakb@iitgn.ac.in

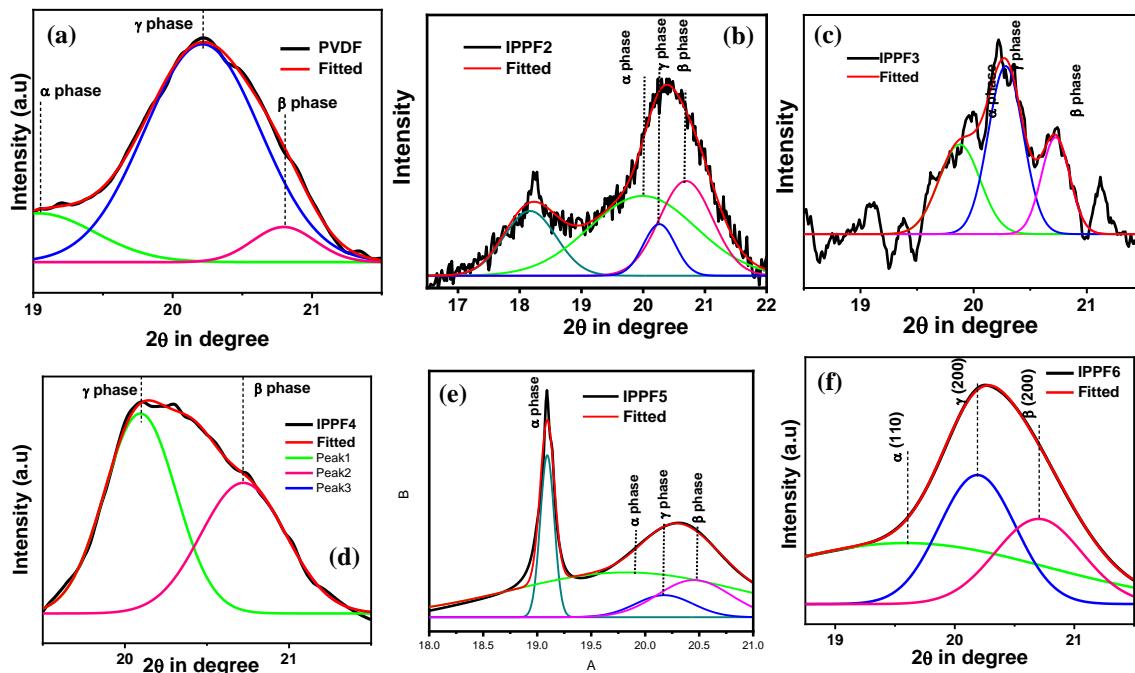


Figure SI: (a)-(f) The deconvoluted XRD peak profiles are showing the peaks corresponding to α , β and, γ phases in PVDF and all composite films.

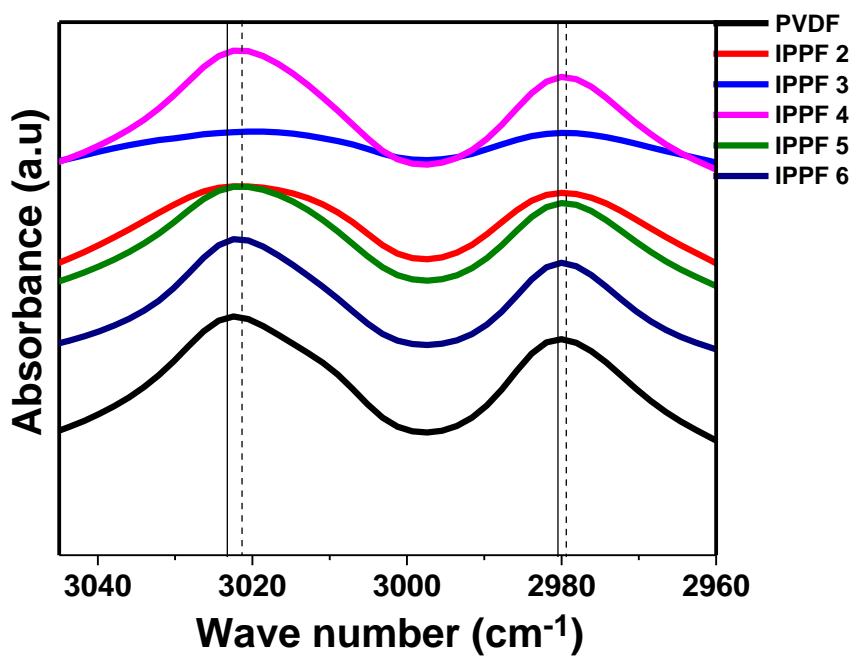


Figure S2: Shift in FTIR stretching vibration of PVDF and all composite films.

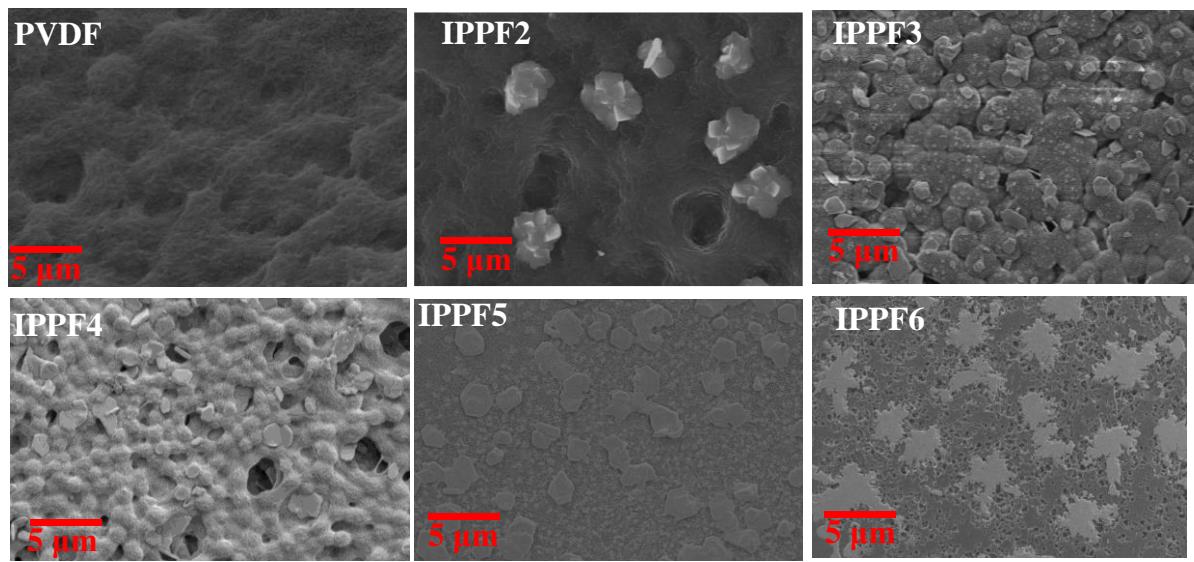


Figure S3: FESEM image of (a) pristine PVDF and (b) IPPF2, (c) IPPF3, (d) IPPF4, (e) IPPF5, (f) IPPF6.

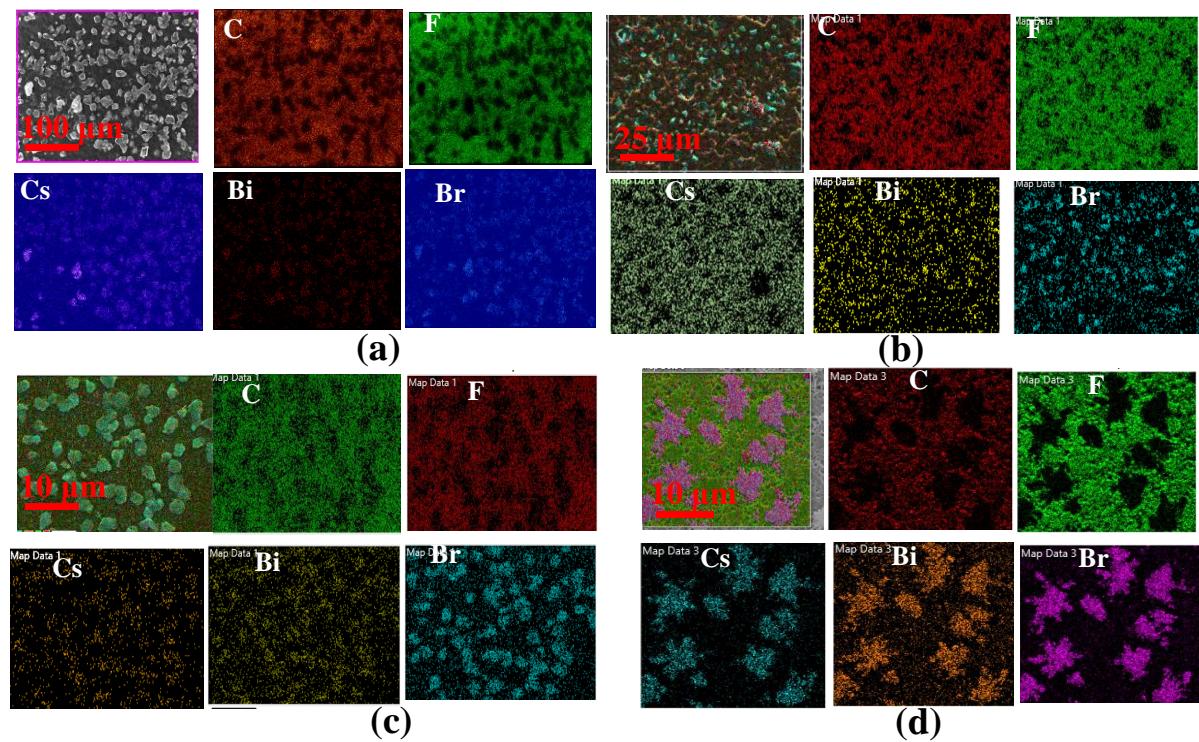


Figure S4: EDX mapping of the composite films (a) IPPF2, (b) IPPF3, (c) IPPF5, (d) IPPF6.

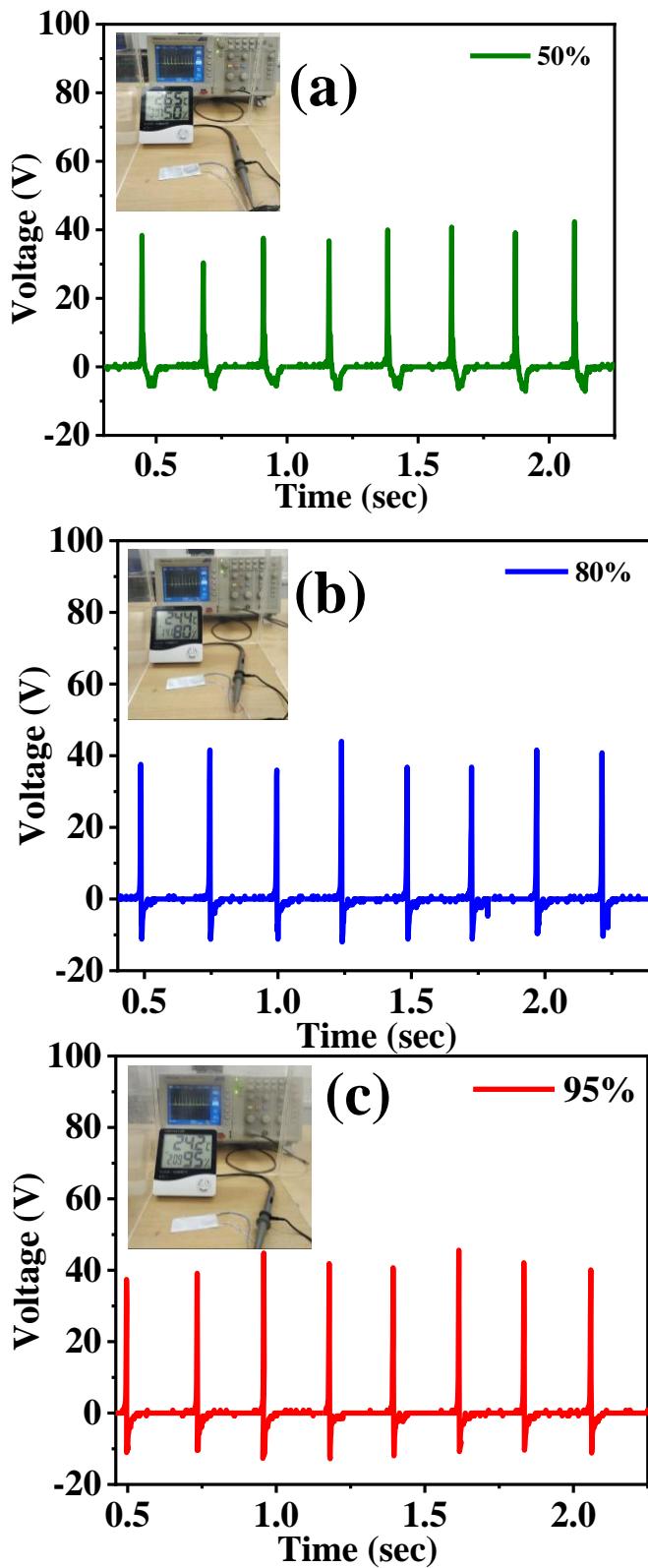


Figure S5: The performance of the nanogenerator with the humidity of the environment from (a) 50% to (b) 80%, and finally to (c) 95%. Inset shows real-time images of the operation of the nanogenerator device in controlled humidity conditions.

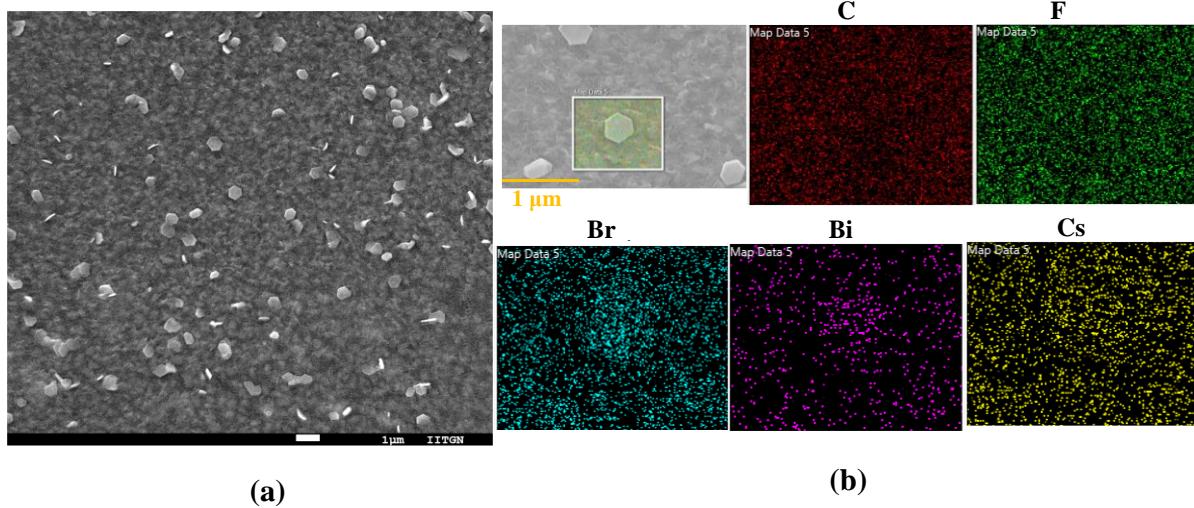


Figure S6: (a) FESEM image and (b) EDX mapping of IPPF4 after long cycle operation.

Table S1: Piezoelectric co-efficient comparison

Material	Piezoelectric constant (d_{33}) (pC/N)	References
$\text{CH}_3\text{NH}_3\text{PbI}_3$	5.12	1
ZnO	3	2
GaN	3.1	3
PZT	290	4
BaTiO_3	190	5
LiNbO_3	11	6
$\text{K}_{0.8}\text{Na}_{0.2}\text{NbO}_3$	110	7
FAPbBr ₃	25	8
MDABCO-NH ₄ I ₃	14	9
(4-aminotetrahydropyran) ₂ PbBr ₄	76	10
Insitu PVDF@Cs₃Bi₂Br₉	10	This work

Table S2: Nanogenerator performance comparison

Polymer	Filler/ Device structure	Pressure/ Force	Output voltage	Current / Current density	Application	Stability / Cycle	Ref.
PVDF	FAPbBr ₃	Finger imparting	26.2 V	2.1 μA	LCD screen, speaker etc.	4 weeks	11
PVDF	BaTi _(1-x) Z _x O ₃ (BTZO)		11.9 V	1.35 μA			12
PVDF - TrFE)	CsPbBr ₃ QDs	0.6 MPa	11.5 V		Powering LEDs	1200 cycles	13
PEDOT - coated PVDF		8.3 kPa	48 V	6 μA	Weight Measureme nt Mapping, Vibration Sensor	21000 cycles	14
PDMS	ZnSnO ₃	Repeating finger	40 V	0.4 μA	Glowing of LEDs		15
PVDF	DNA	13 kPa	6 V	0.088 μA	Glowing of LEDs		16
PDMS	PZT	Bending	10 V	1.3 μA	Glowing of LEDs	3 days / 6000 cycle	17
PVDF	MAPbBr ₃	Finger touch	5 V	60 nA	Responses observed from NG as different letters	3600 cycles	18
PDMS	FAPbBr ₃		8.5 V	3.8 μA/cm ²			19
PVDF	Cs₃Bi₂Br₉	Biomecha nical Motions	40 V	4.1 μA	LED glowing	1000 cycles/ 6 months	This work

Table S3: Different configurations of a single strand of β -PVDF and the perovskite interface for the Bi and CsBr₃ terminations of the (0001) surface of Cs₃Bi₂Br₉.

Interface Configuration	Binding energy (eV/monomer)
Bi-termination	
	1.13
	-0.70
	-0.66
	-0.56
	-0.53
CsBr₃ termination	
	-2.13
	-1.81

	-1.59
	-1.12
	-0.45

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